

# Zero Ripple Current and Low THD With iW3623 for T8 LED driver

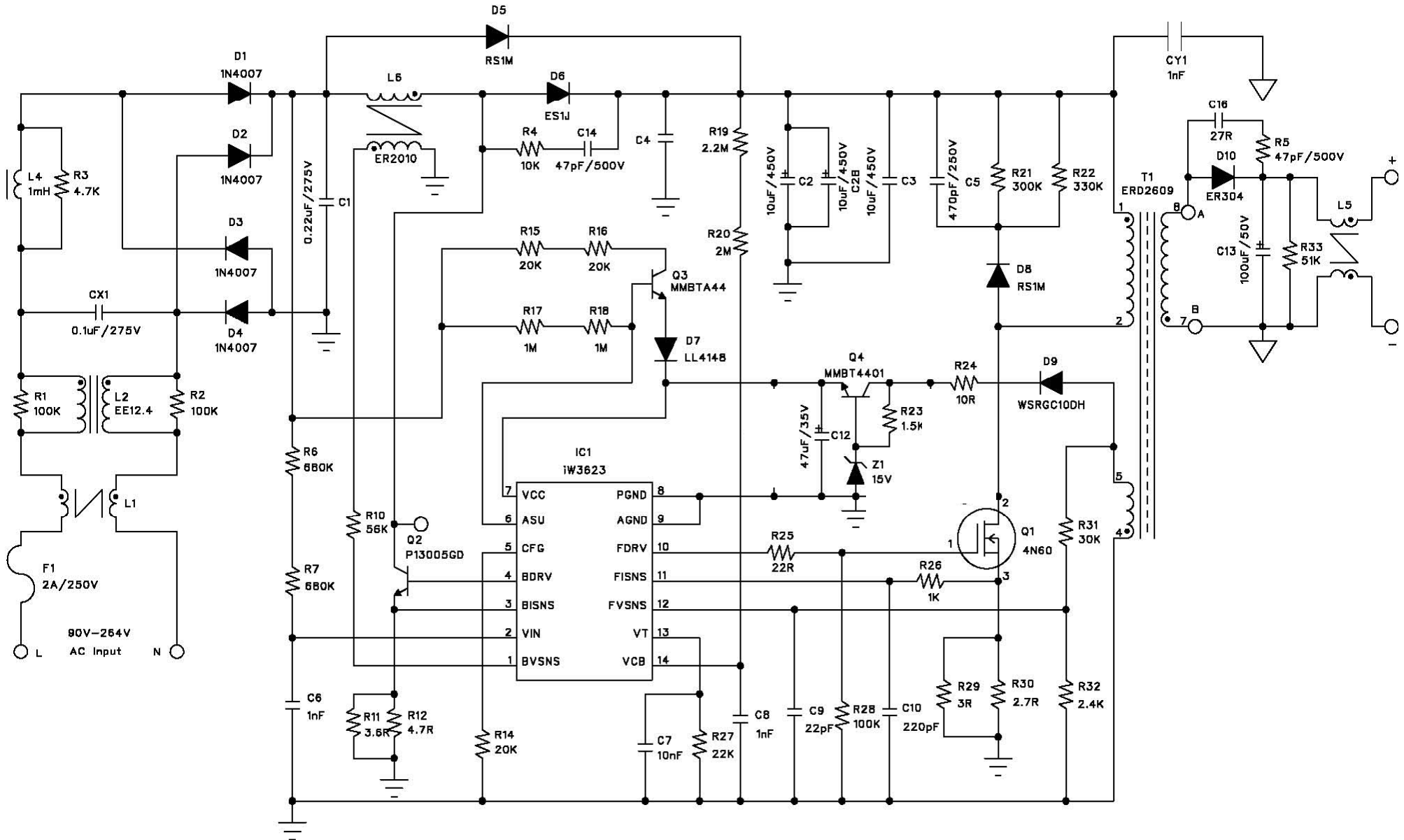
## General Design Specification:

1. AC Input Range 90-264Vac, Isolated ac-dc offline, 12LEDS, Output 450mA
2. For Isolated Applications
3. High Efficiency, High power Factor and Least Parts Solution
4. Temperature degrade control to adjust the LED.
5. Primary-only Sensing eliminates opto-isolator feedback and simplifies design

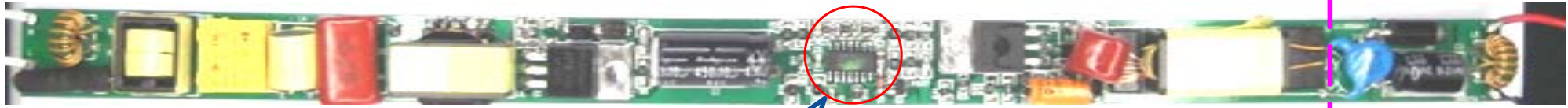
# 1. Specification

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	$V_{IN}$	90		264	V <sub>AC</sub>	2 Wire
Frequency	$f_{LINE}$	47	50/60	63	Hz	
Output						
Output Voltage	$V_{OUT}$		40		V	Measured at the end of PCB
Output Current	$I_{OUT}$		0.45		A	
Output Ripple Current	$I_{RIPPLE}$		30		mA <sub>P-P</sub>	Set oscilloscope at 20MHz bandwidth.
Total Output Power						
Continuous Output Power	$P_{OUT}$		18		W	
Performance Factor	$PF$	0.9			A	
Active Mode Efficiency	$\eta$		86		%	Measured at end of PCB, $V_{IN} = 230VAC$ ( $T_{AMB} = 25\text{ }^{\circ}C$ ).
Environmental						
THD	THD			15	%	
Conducted EMI		Meets CISPR22B / EN55022B				
Safety		Designed to meet IEC950, UL1950 Class II				
Ambient Temperature	$T_{AMB}$	0		40	$^{\circ}C$	Free convection, sea level

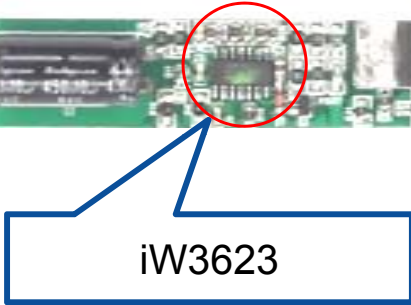
# 2. Schematic



# 3. Circuit Board Photograph



AC  
Input

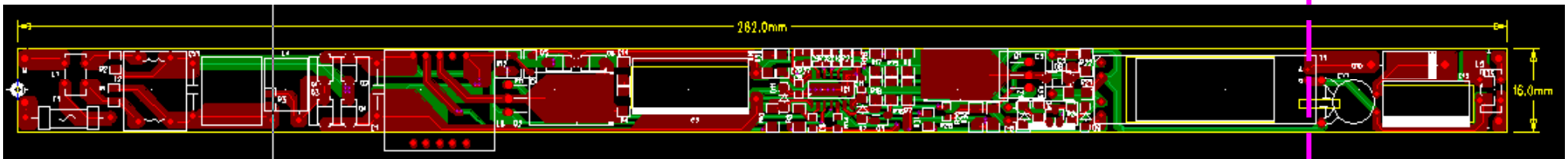


DC  
output  
To LED



Primary

Secondary



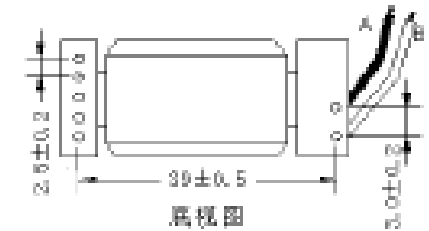
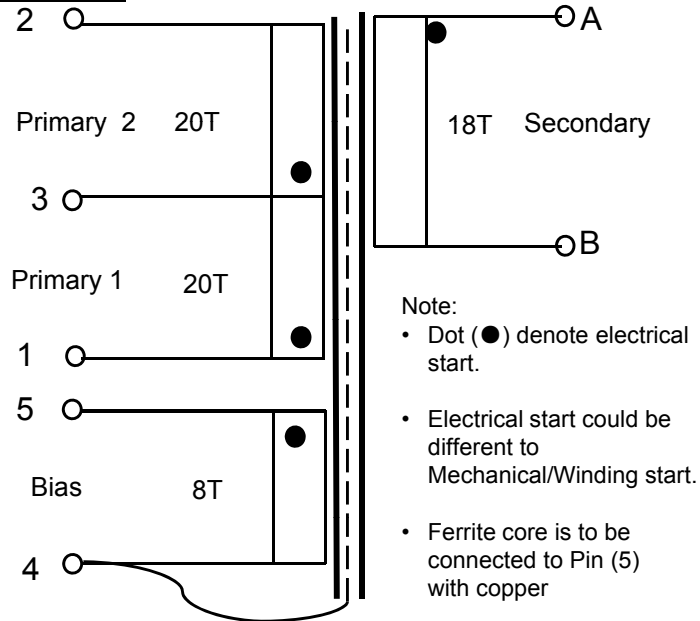


# 4.BOM

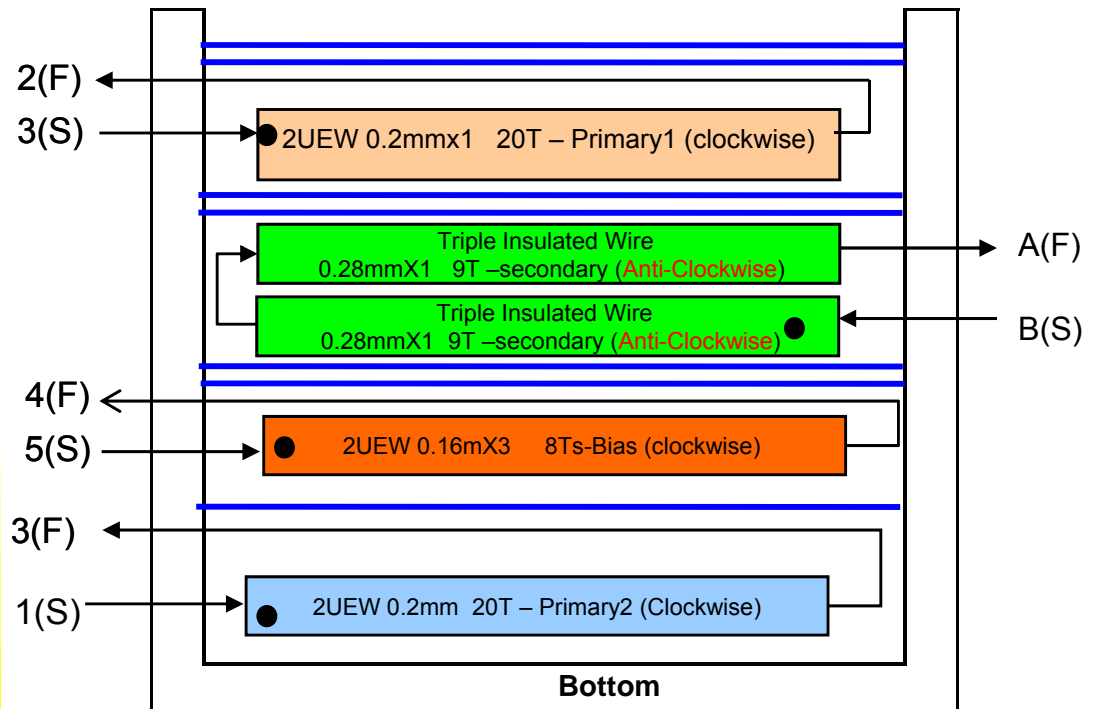
Item	Reference	Description	Qty	Item	Reference	Description	Qty
1	IC1	iW3623-00, Digital PWM Controller, Dimmable, SO-14	1	27	R6	21Ω, ±5%, SMD-1206	1
2	CX1	0.1uF, 275V, X2	1	28	R20	2MΩ, ±5%, SMD-1206	1
3	C1	0.22uF, 400V, CBB21	1	29	R21, R22	330KΩ, ±5%, SMD-1206	2
4	C3	0.1uF, 400V, CBB21	1	30	R23	1.0KΩ ±5%, SMD-0603	1
5	C2	10uF, 450V, E-CAP	1	31	R24	10Ω ±5%, SMD-0603	1
6	C12	47uF, 35V, E-CAP	1	32	R28	100KΩ ±5%, SMD-0603	1
7	C13	100uF, 50V, E-CAP	1	33	R29, R30	2.7Ω ±1%, SMD-1206	2
8	C9	22pF, 25V, X7R, SMD-0603	1	34	R31	30KΩ ±1%, SMD-0603	1
9	C6, C8	1nF, 25V, X7R, SMD-0603	2	35	R32	2.4KΩ ±1%, SMD-0603	1
10	C4	10nF, 500V, X7R, SMD-1206	1	36	F1	T2A250V	1
11	C7	10nF, 25V, X7R, SMD-0603	1	37	D1, D2, D3, D4	1N4007, DO-41(M7)	4
12	C5	470pF, 250V, X7R, SMD-0805	1	38	D9	SRGC10DH(FR102), 1A, 200V, 1206-S	1
13	C4, C16	47pF, 500V, X7R, SMD-1206	2	39	D5, D8	RS1M, 1A, 1000V, S0D-123	2
14	R1, R2	100KΩ ±5%, SMD-1206	2	40	D6	ES1J, 1A, 600V, SMA	1
15	R3	4.7KΩ ±5%, SMD-0805	1	41	D10	ER304, 2A, 400V, DO-201	1
16	R6	680KΩ ±5%, SMD-1206	1	42	D7	LL4148, 0.15A, 100V, LL-34	1
17	R7	620KΩ ±5%, SMD-1206	1	43	Z1	Zener, ZMM15B, 15V, LL-34	1
18	R8	0Ω ±5%, SMD-1206	1	44	Q1	4N60.4A, 600V, TO-220	1
19	R10	56KΩ ±5%, SMD-0805	1	45	Q3	MMBTA44, NPN, 400V, SOT-23	1
20	R11	3.6Ω ±5%, SMD-1206	1	46	Q2	3DD13005ED, NPN, 4A 700V, TO-126	1
21	R4	20kΩ ±5%, SMD-1206	1	47	L1	Common Mode Inductor T8*3*3 15uH	1
22	R14, R27	20kΩ ±5%, SMD-0603	2	48	L2	EE12.4, 25mH	1
23	R15, R16	20KΩ ±5%, SMD-1206	2	49	L4	8*10, 1.0mH	1
24	R17, R18	1MΩ ±5%, SMD-1206	2	50	L6	ER2010, L=0.9mH	1
25	R19	2.2MΩ, ±5%, SMD-1206	1	51	L5	Common Mode Inductor T8*4*3 17uH	1
26	R26	470Ω ±5%, SMD-0603	1	52	T1	Transformer ERD2610 L=1.0~1.1mH	1

# 5. Transformer Construction

## SCHEMATIC



Rotating direction of winding machine



## ELECTRICAL SPECIFICATIONS:

1. Primary Inductance ( $L_p$ ) = 1.1mH @10KHz
2. Primary Leakage Inductance ( $L_k$ ) <= 50uH @10KHz
3. Electrical Strength = 3KV, 50/60Hz, 1Min

## MATERIALS:

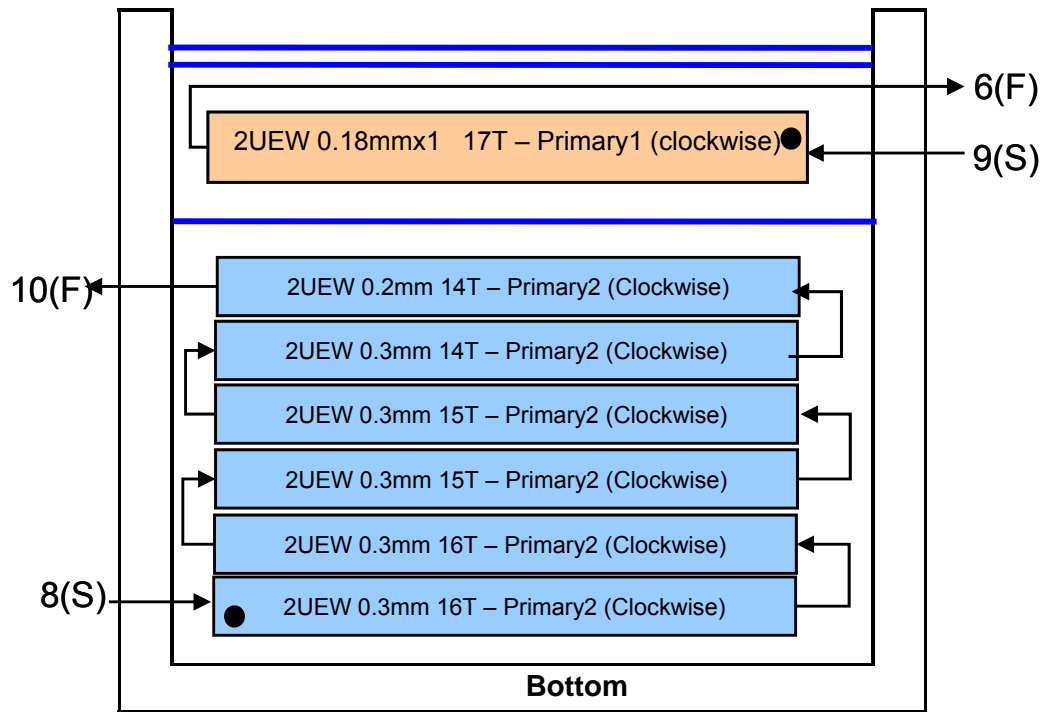
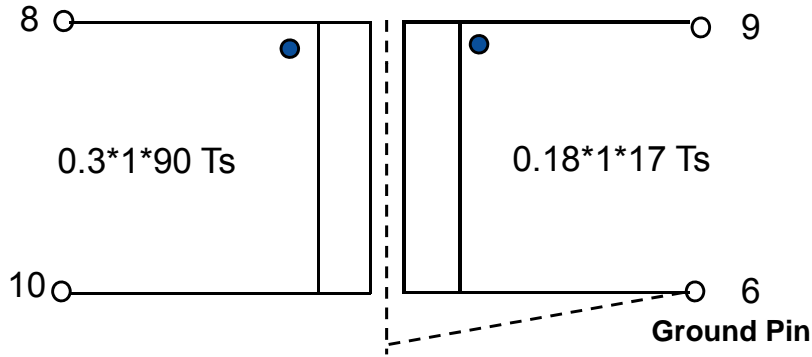
1. Core : ERD26 (Ferrite Material TDK PC40 or equivalent)
2. Bobbin : ERD26, Horizontal, Primary=5, Secondary=2
3. Magnet Wires (Pri) : Type 2-UEW
4. Magnet Wire (Sec) : Triple Insulated Wires
5. Layer Insulation Tape : 3M1298 or equivalent.

## FINISHED :

1. Cut remained of 1/2 Pin3, after wires termination
2. Core is connected to PRI-GND pin4.
3. Varnish the complete assembly

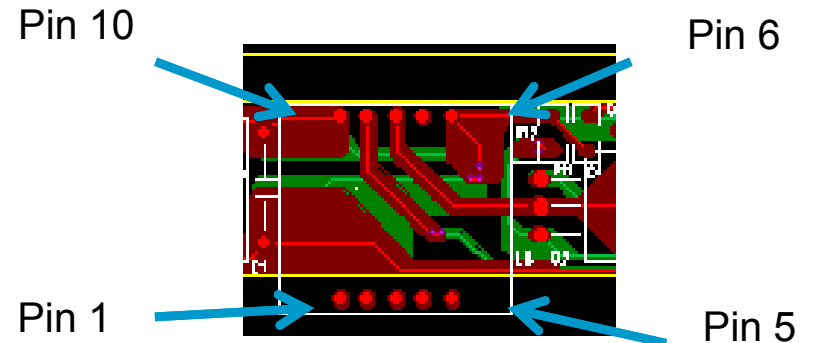
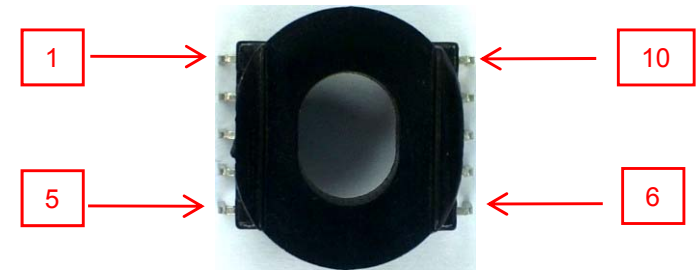
# 6.PFC Inductor

## SCHEMATIC



## ELECTRICAL SPECIFICATIONS:

1. Inductance ( $L_{p8-10}$ ) = 0.9mH @10KHz
2. Core : ER2010 (Ferrite Material TDK PC40 or equivalent)
3. Bobbin : ER2010, Horizontal
4. Ferrite core is connected to Pin 6 after assembling
5. Cut Pin 1,2,3 ,4,5,7,9 after wires termination
6. Varnish the complete assembly

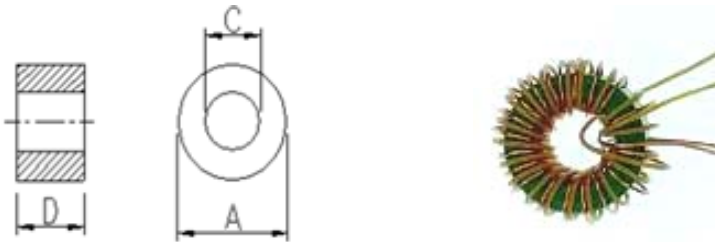


# 7. Common Mode Inductor L1

## Properties of B&F Ferrite - Nickel Zinc (Ni-Zn)

Material	$\mu_i$	Bms(Gs)	Hc(Oe)	Br(Gs)	Tc(°C)	$\rho (\Omega \cdot \text{cm})$	Frequency (MHz)	$\alpha \text{ ur } \times 10^{-6}/^\circ\text{C}$
B29	800	2900	0.30	1420	150	$1 \cdot 10^7$	0.1~0.7	25~45

## EMI Toroidal Core ( T Type )



Dimensions 尺寸 ( mm )

Core Size	Conf.	A	D	C	Fig
T 8.0x4.0x3.0		8.0±0.3	4.0±0.3	3.0±0.2	1,2,3

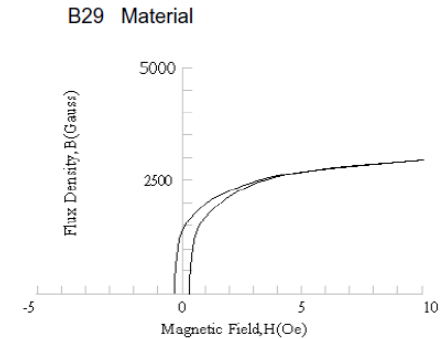
Ferrite core : Ni -Zn T8\*4\*3

Wire gauge: 0.3mm, 8Turns (Triple Insulated Wire)

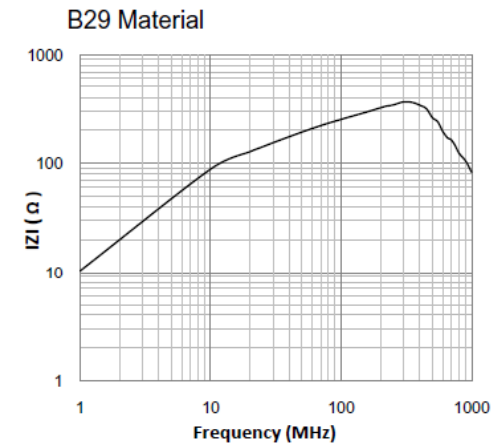
Inductance @10kHz, 1V: 25uH +/-10%

DCR: 0.12 OHM +/-20%

## Saturation Flux Density (Ni-Zn)



## Impedance Vs Frequency Curve (Ni-Zn)



**B.F.**

### Contacts Information

Company Name : Bead & Ferrite Electronics (HK) Ltd.  
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 Fax No. : ( 852 ) 2693 6202  
 Email Address : [bf@bnf.com.hk](mailto:bf@bnf.com.hk)  
 Home Page : [www.bnf.com.hk](http://www.bnf.com.hk)  
 Address : RM. 16-17, 15/F., Block C, Goldfield Ind. Centre,  
 No.1 Sui Wo Road, Fo Tan, N.T. Hong Kong

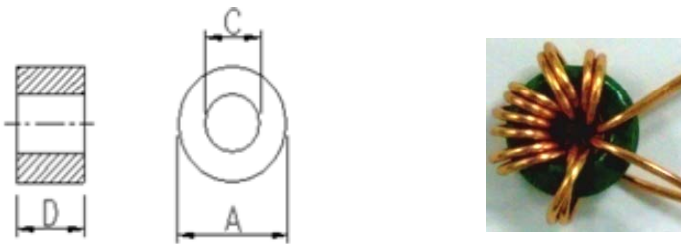


# 8. Common Mode Inductor L5

## Properties of B&F Ferrite - Nickel Zinc (Ni-Zn)

Material	$\mu_i$	Bms(Gs)	Hc(Oe)	Br(Gs)	Tc(°C)	$\rho (\Omega \cdot \text{cm})$	Frequency (MHz)	$\alpha \text{ ur } \times 10^{-6}/^\circ\text{C}$
B29	800	2900	0.30	1420	150	$1 \cdot 10^7$	0.1~0.7	25~45

## EMI Toroidal Core ( T Type )



Dimensions 尺寸 ( mm )

Core Size	Conf.	A	D	C	Fig
T 8.0x4.0x3.0		8.0±0.3	4.0±0.3	3.0±0.2	1,2,3

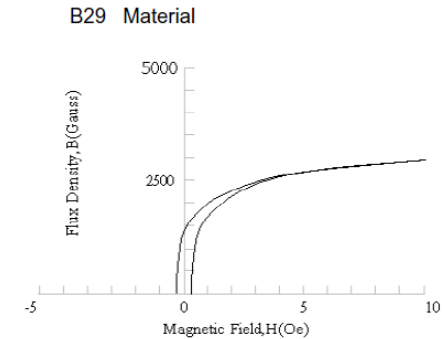
Ferrite core : Ni -Zn T8\*4\*3

Wire gauge: 0.45mm, 6Turns

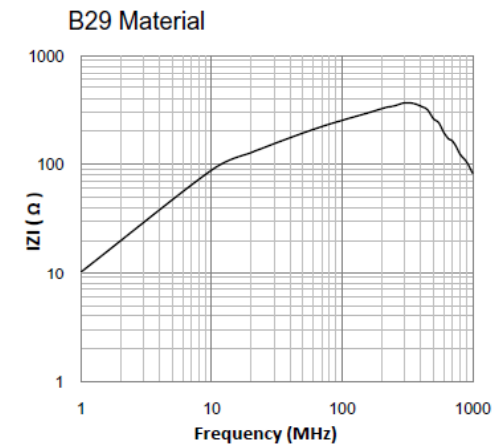
Inductance @10kHz, 1V: 17uH +/-10%

DCR: 0.1 OHM +/-20%

## Saturation Flux Density (Ni-Zn)



## Impedance Vs Frequency Curve (Ni-Zn)



**B.F.**

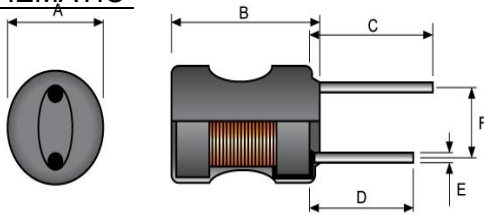
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 No.1 Sui Wo Road, Fo Tan, N.T. Hong Kong

# 9.EMI Inductor

## 1. Differential Mode Inductor L4

SCHEMATIC



Ferrite core size : AxB 8x10mm

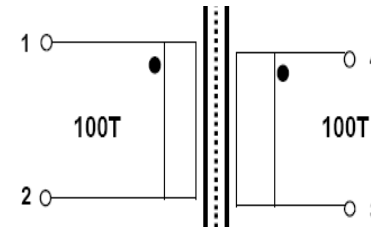
Wire gauge: 0.23mm, 185 Turns

Inductance @10kHz, 1V: 1mH +/-10%

DCR: 1.4 OHM +/-20%

## 2.Common Choke L1 for EMI

SCHEMATIC



Ferrite core : EE12.4  $\mu \geq 10k$

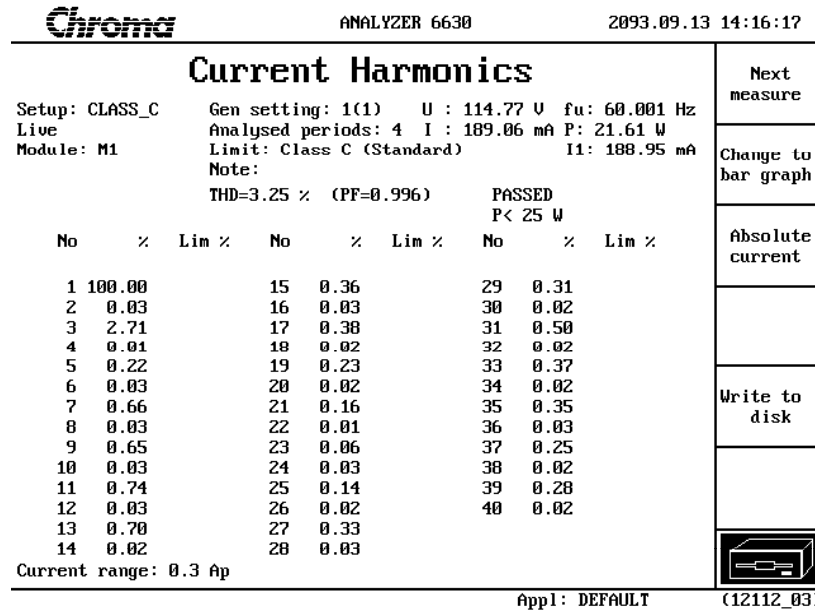
Wire gauge: 0.2mm, 110Turns

Inductance @10kHz, 1V: 25mH +/-20%

DCR: 1.2OHM +/-20%

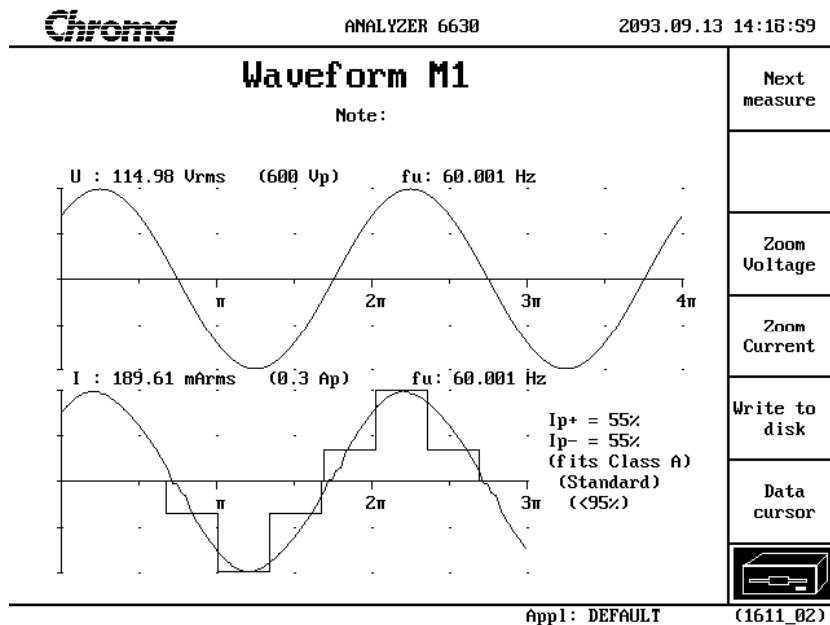


# 11. Harmonic and current waveform



Harmonics current @115Vac \

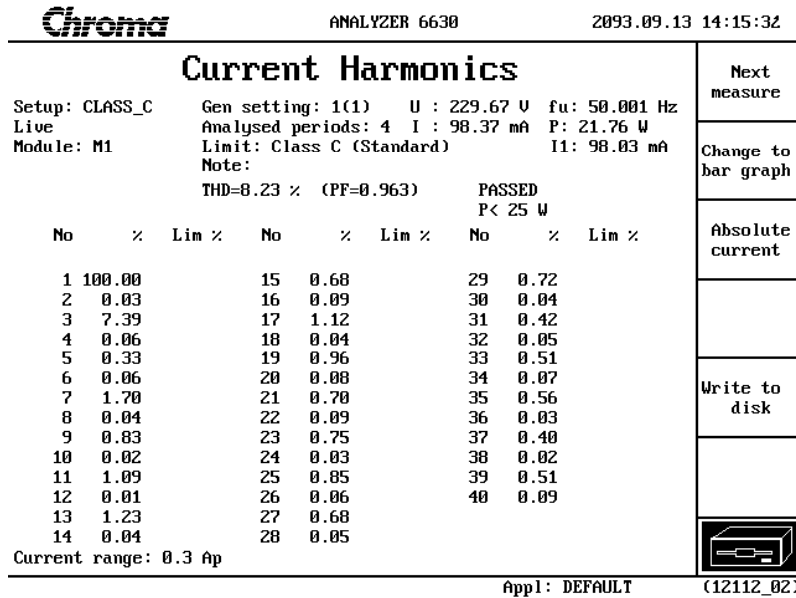
THD=3.25%



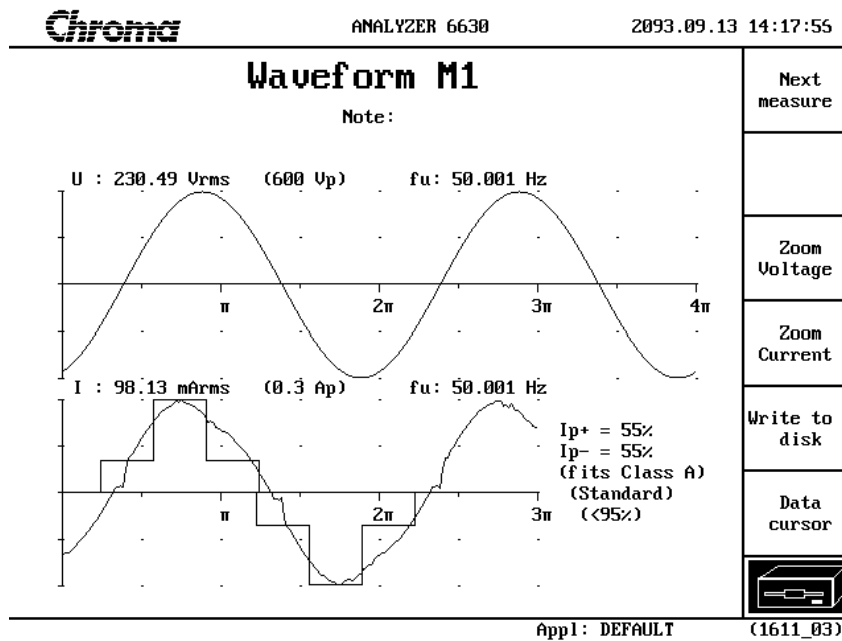
AC current waveform @115Vac

PF=0.996

# 12. Harmonic and current waveform



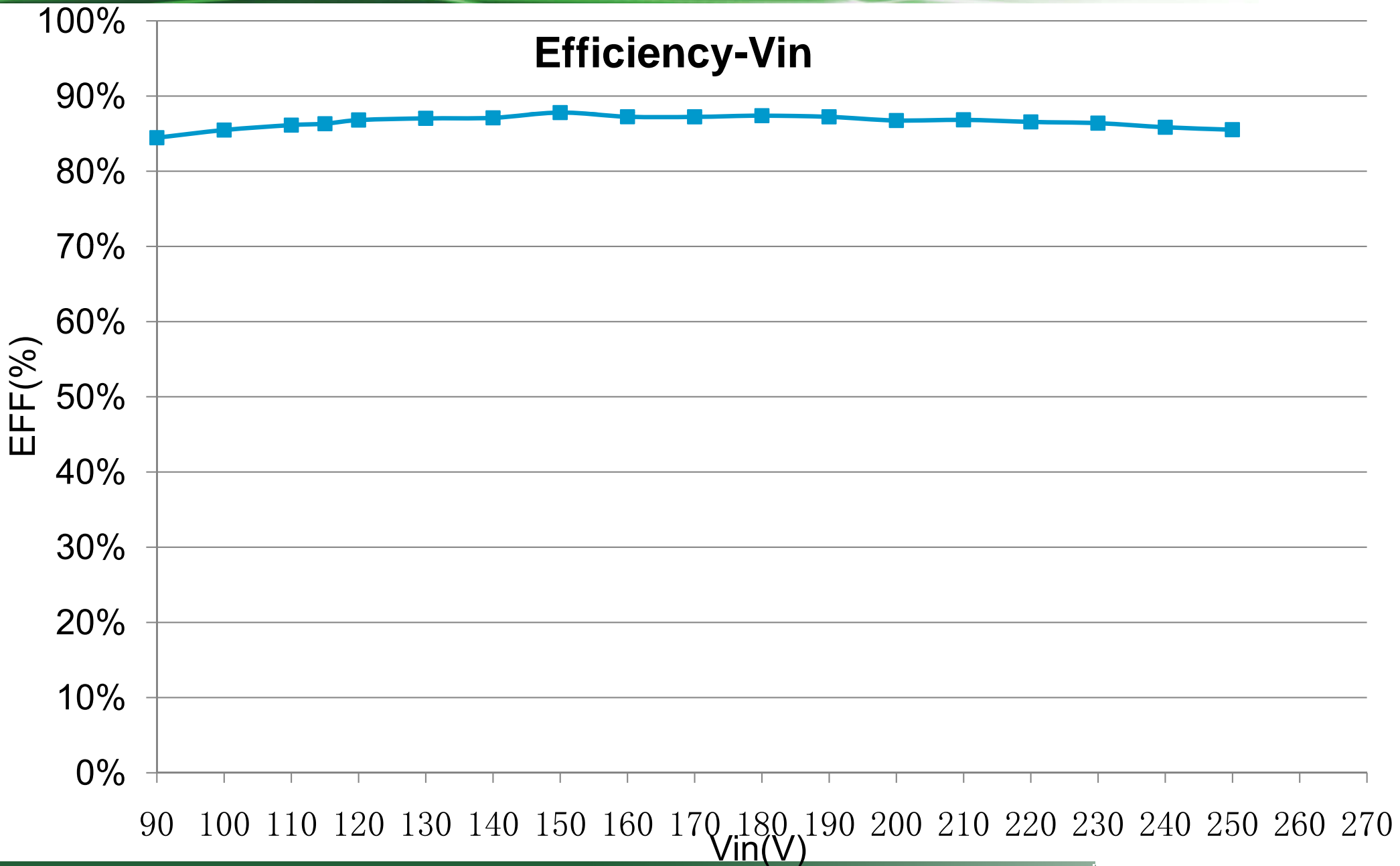
Harmonics current @230Vac  
THD=8.23%



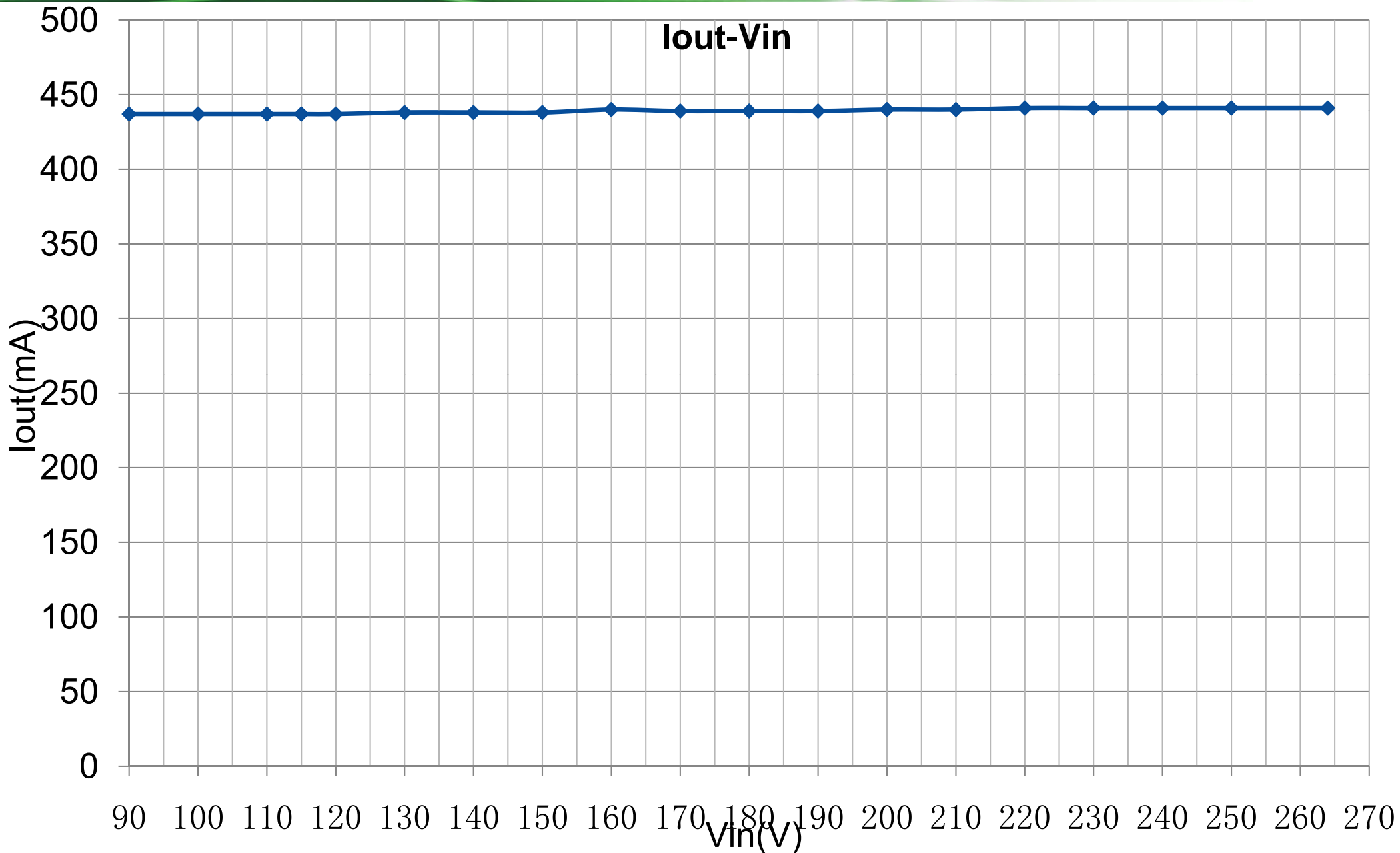
AC current waveform @230Vac  
PF=0.963



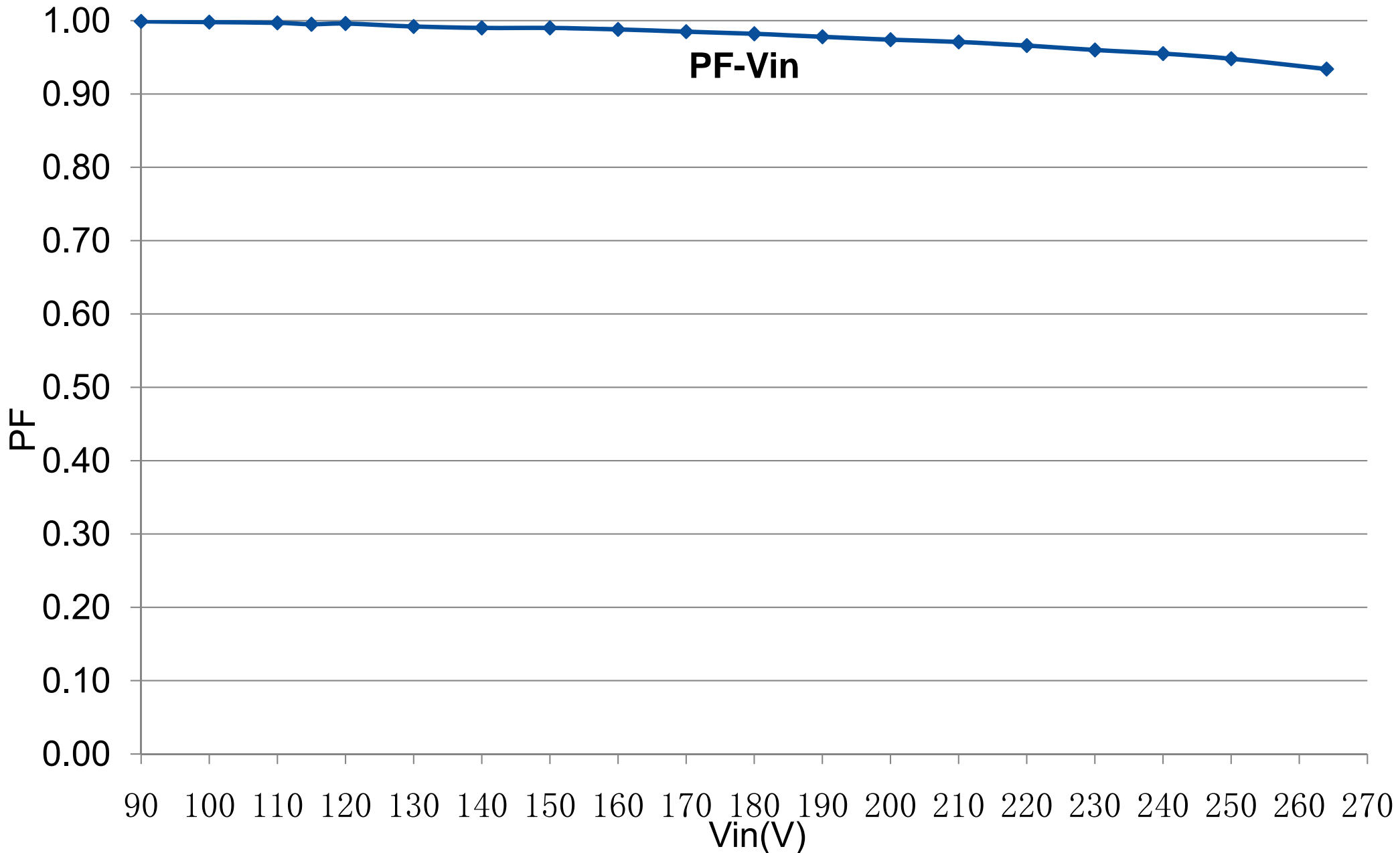
# 13. Variable Input Vs. Efficiency Measurement



# 14. Variable Input Vs. Iout Measurement



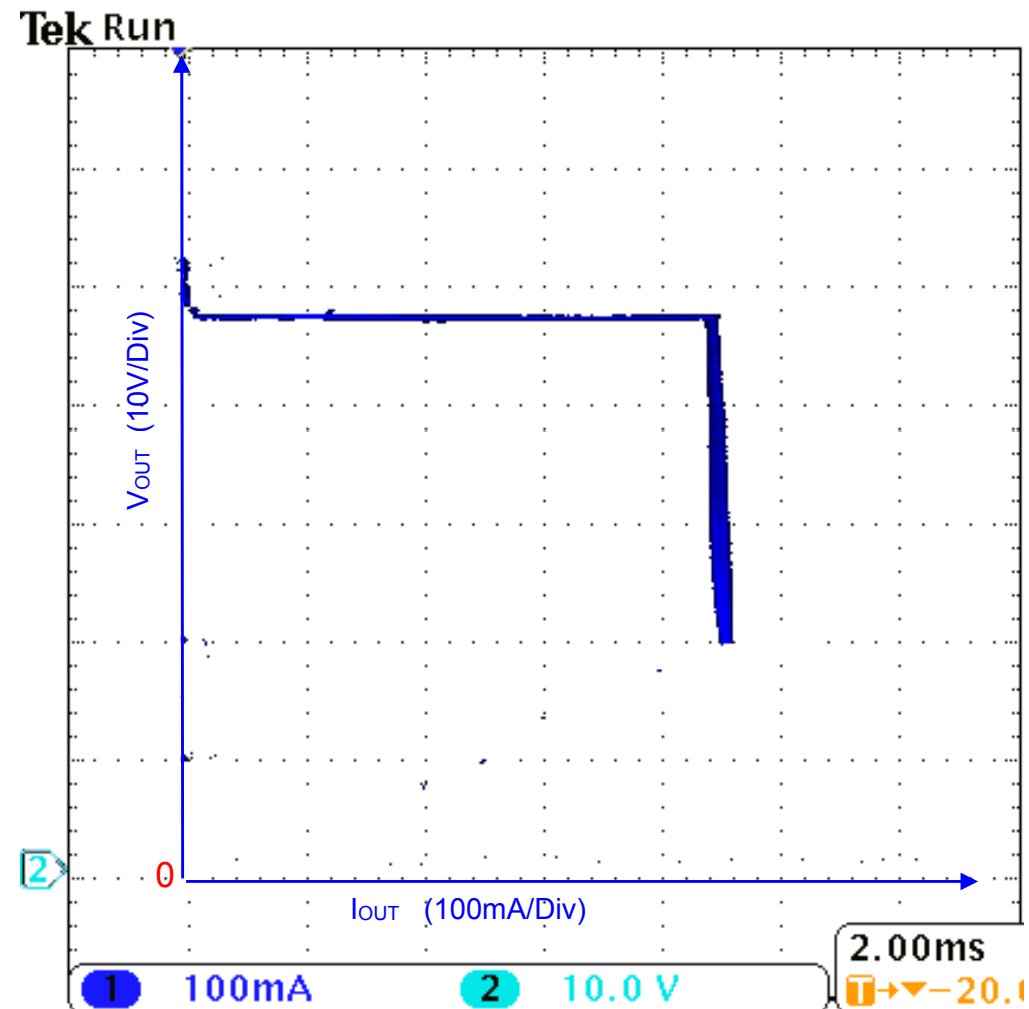
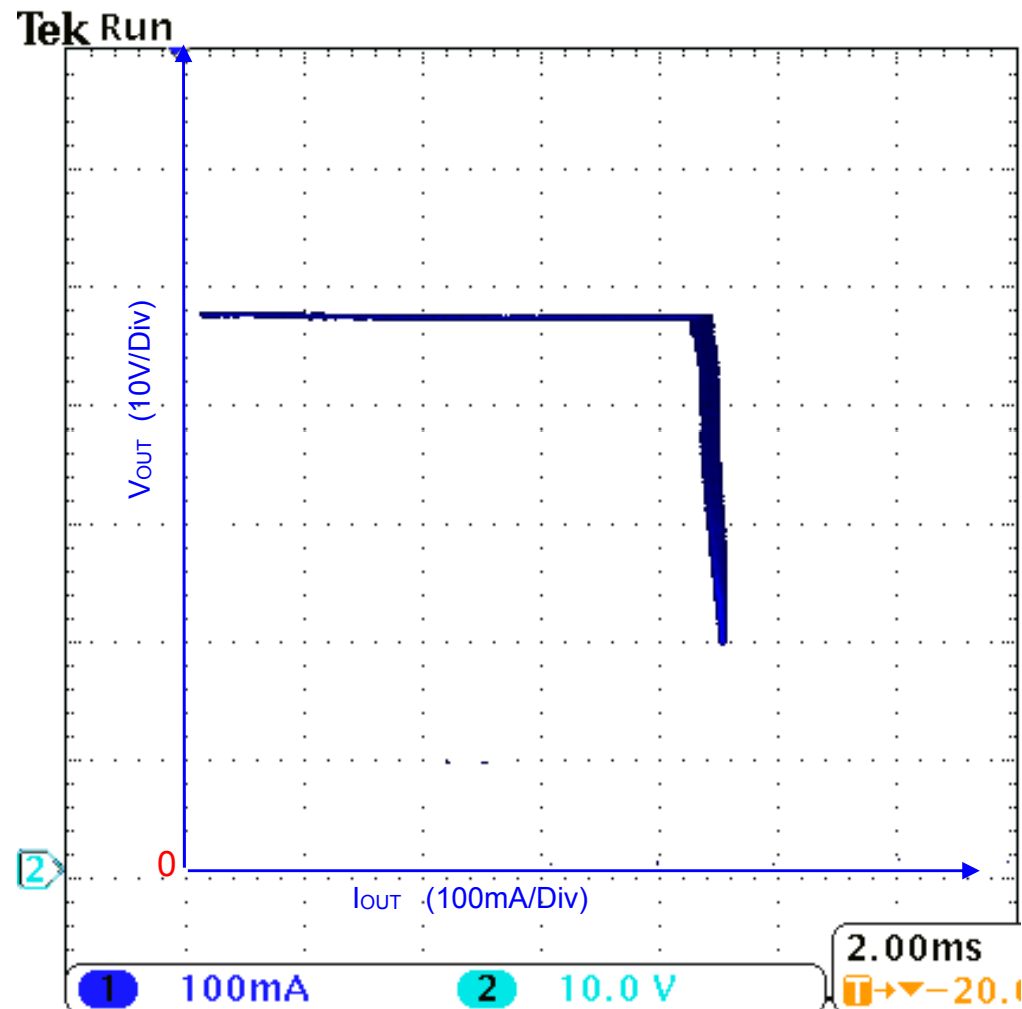
# 15. Variable Input Vs. PF Measurement



# 16. Output VI Characteristics(CR Mode)

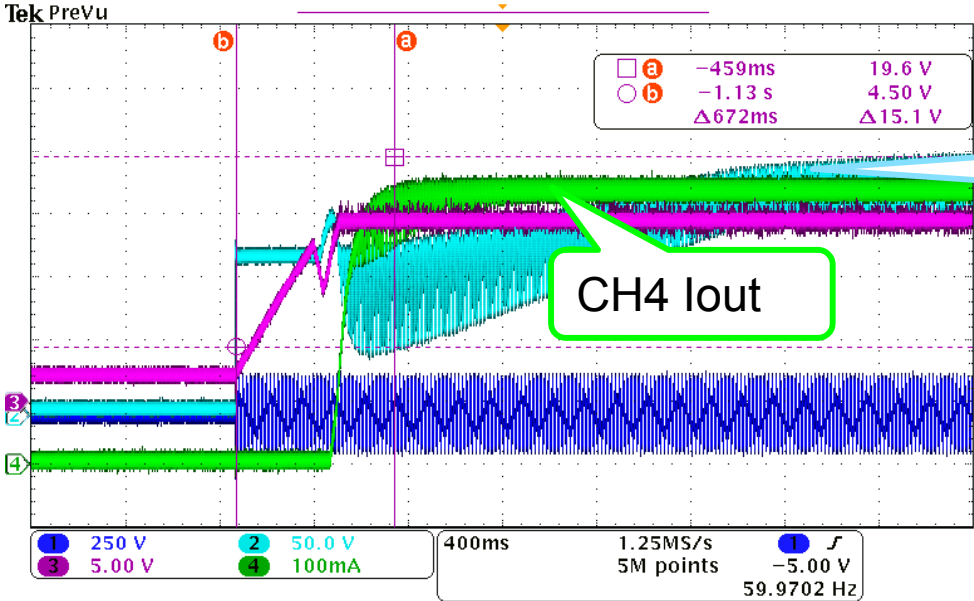
$V_{IN}=90V_{ac}/60Hz$

$V_{IN}=264V_{ac}/50Hz$



\* Note: Output voltage is monitored at end of PCB

# 17. Turn-on Delay Time and Output current overshoot



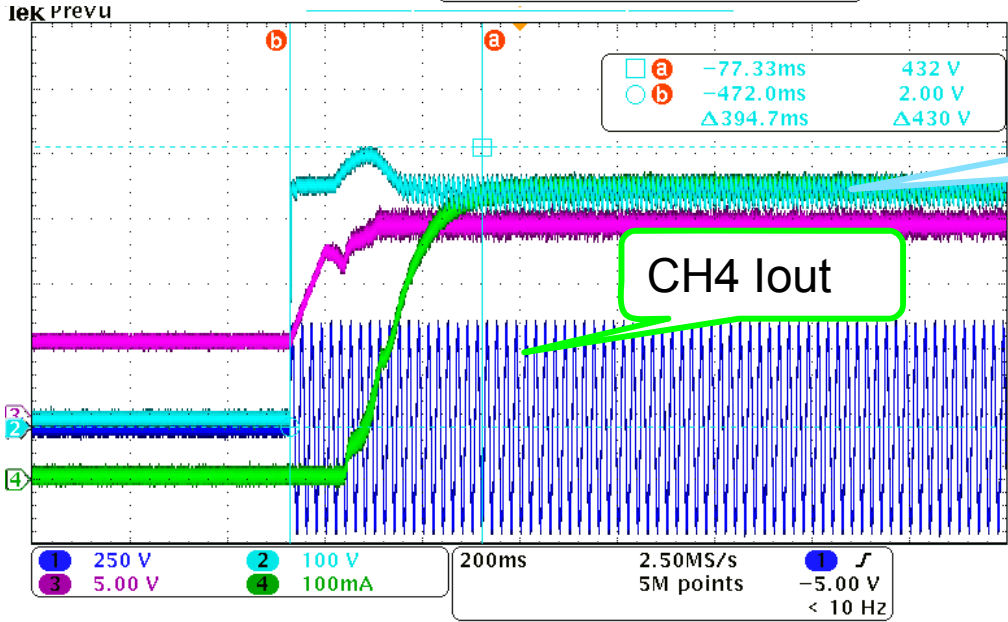
E- CAP VOLTAGE

CH3 VCC

CH1 Vin AC

90V<sub>AC</sub>, Full Load

T<sub>ST\_DELAY</sub>=672mS



E- CAP VOLTAGE

CH3 VCC

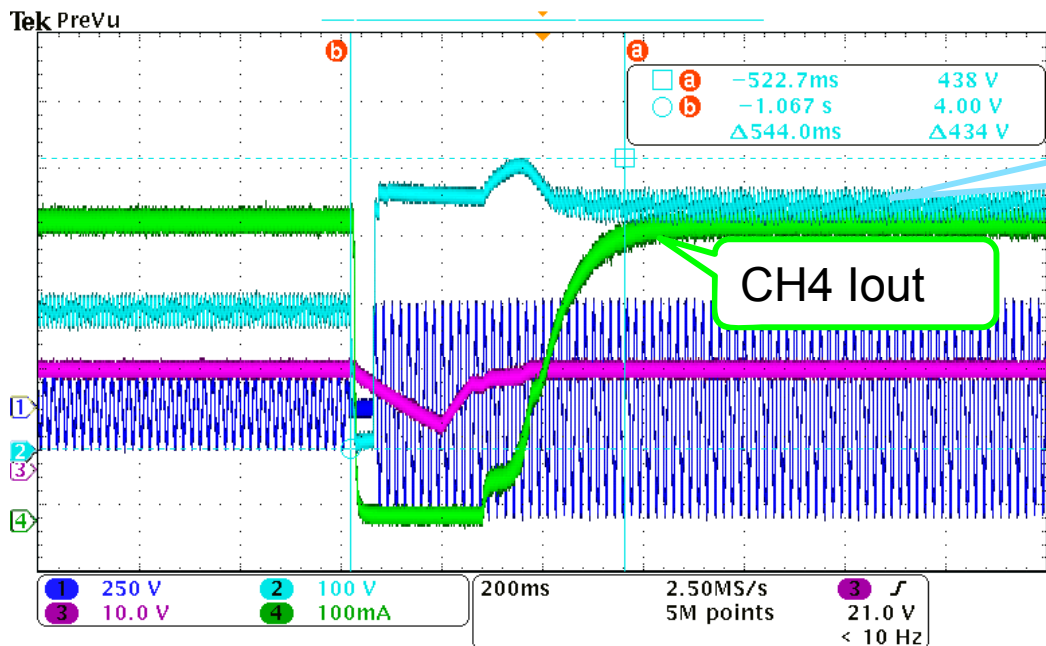
CH1 Vin AC

264V<sub>AC</sub>, Full Load

T<sub>ST\_DELAY</sub>=394.7mS



# 18. Voltage transient , overshoot on voltage on bulk-cap

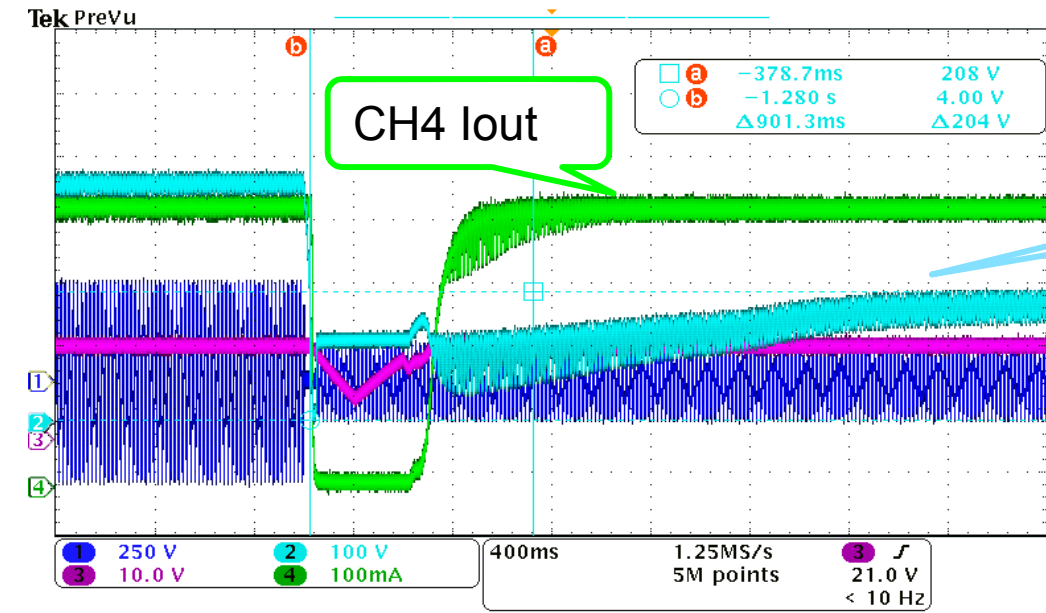


E-CAP VOLTAGE

CH3 VCC

CH1 Vin AC

90 to 264V<sub>AC</sub>, Full Load  
The bulk cap voltage is 434Vmax



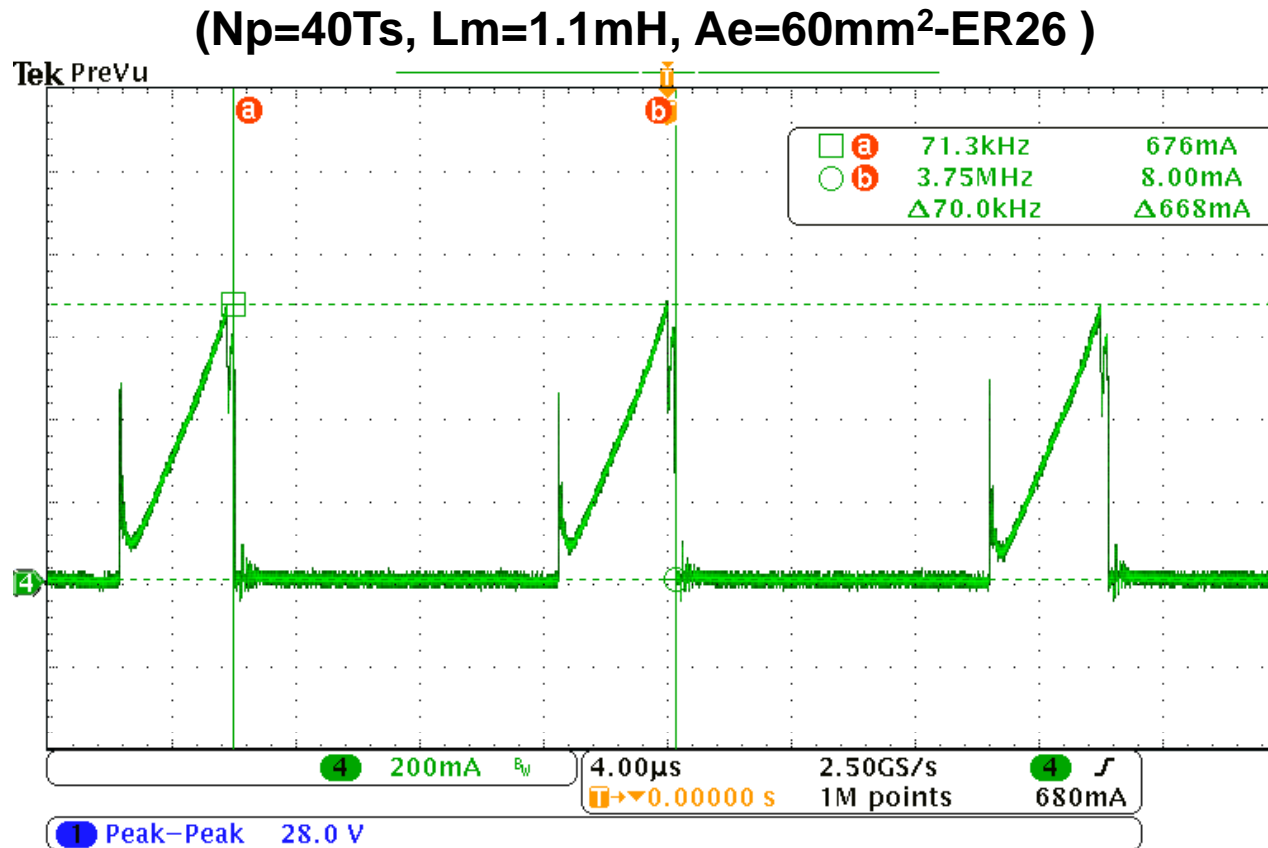
E-CAP VOLTAGE

CH3 VCC

CH1 Vin AC

264 to 90V<sub>AC</sub>, Full Load  
The bulk cap voltage is 204max

# 19. Transformer Flux Density



$I_{PRI}$  is monitored at 90Vac and 0.440A load

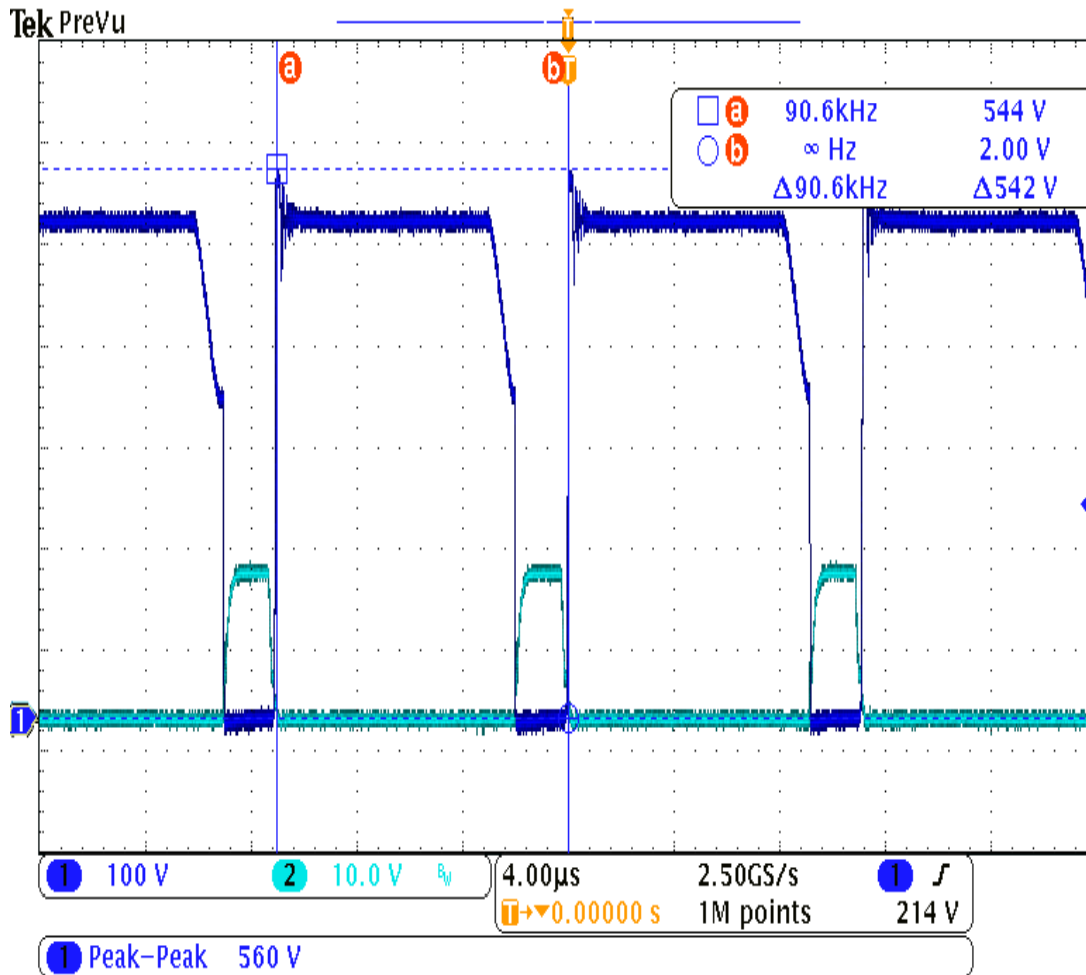
$$I_{PRI} = 668\text{mA}$$

$$B_{MAX} = I_{PRI} * L_{PRI} / (N_P * A_e)$$

$$= (668 * 1.1) / (40 * 60)$$

$$= 0.306\text{Tesla}$$

# 20. Q1 MOSFET $V_{DS}$ Waveform



Test Condition:

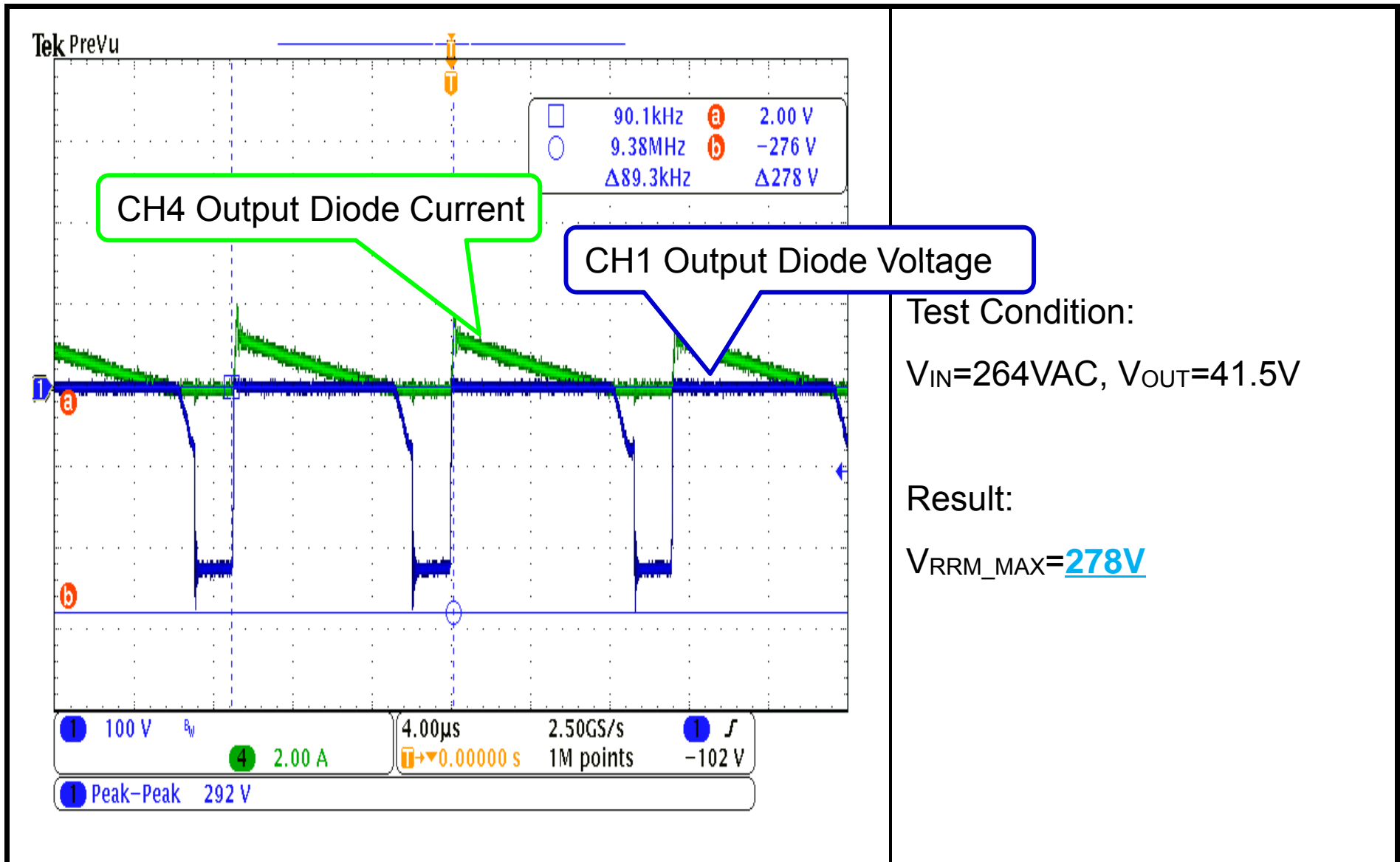
$V_{IN}=264VAC$ ,  $V_{OUT}=41.5V$

Result:

$V_{DS\_MAX}=542V$

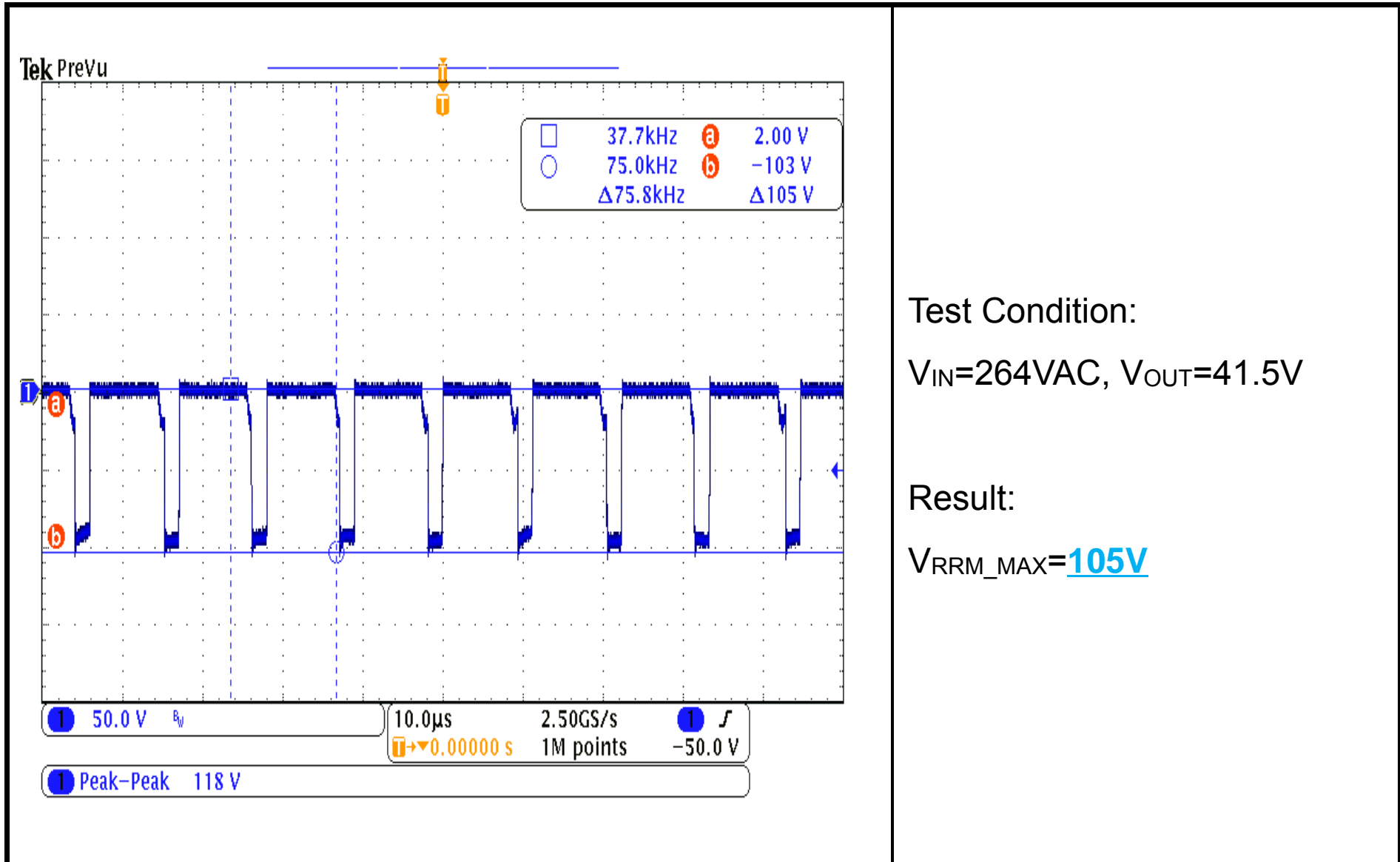
Remark: Mosfet Spec\_\_4A 600V

# 21. Output Diode Waveform



Remark: Diode Spec\_\_3A 300V

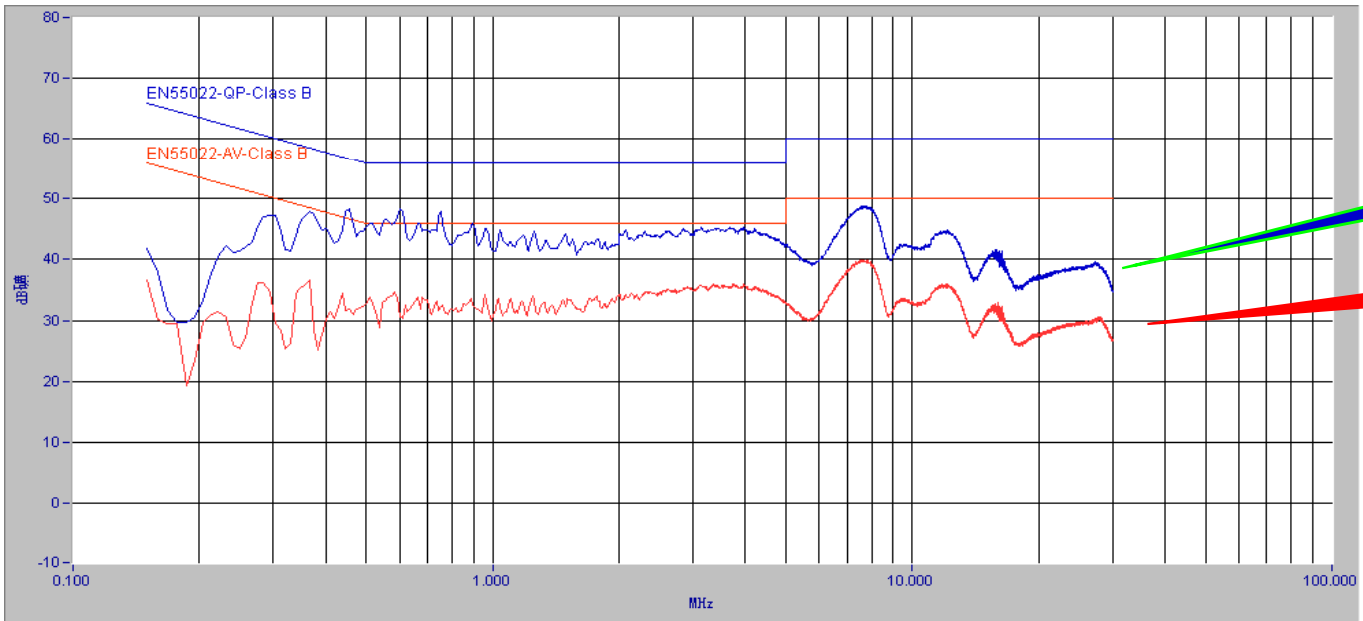
# 22. Vcc Diode waveform



Remark: Diode Spec\_\_1A 200V



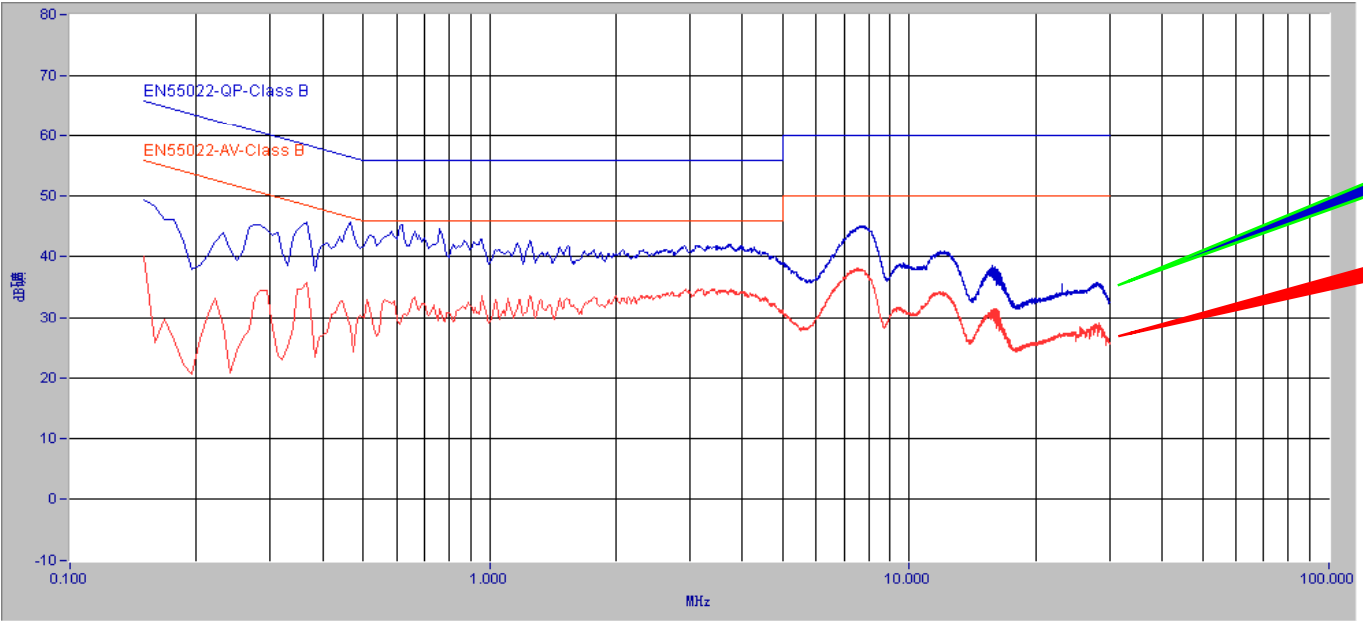
# 23. Conducted EMI (Full Load)



QP Scan  
QP Limit line

AV Scan  
AV Limit line

Input=115VAC  
L line QP&AV scan

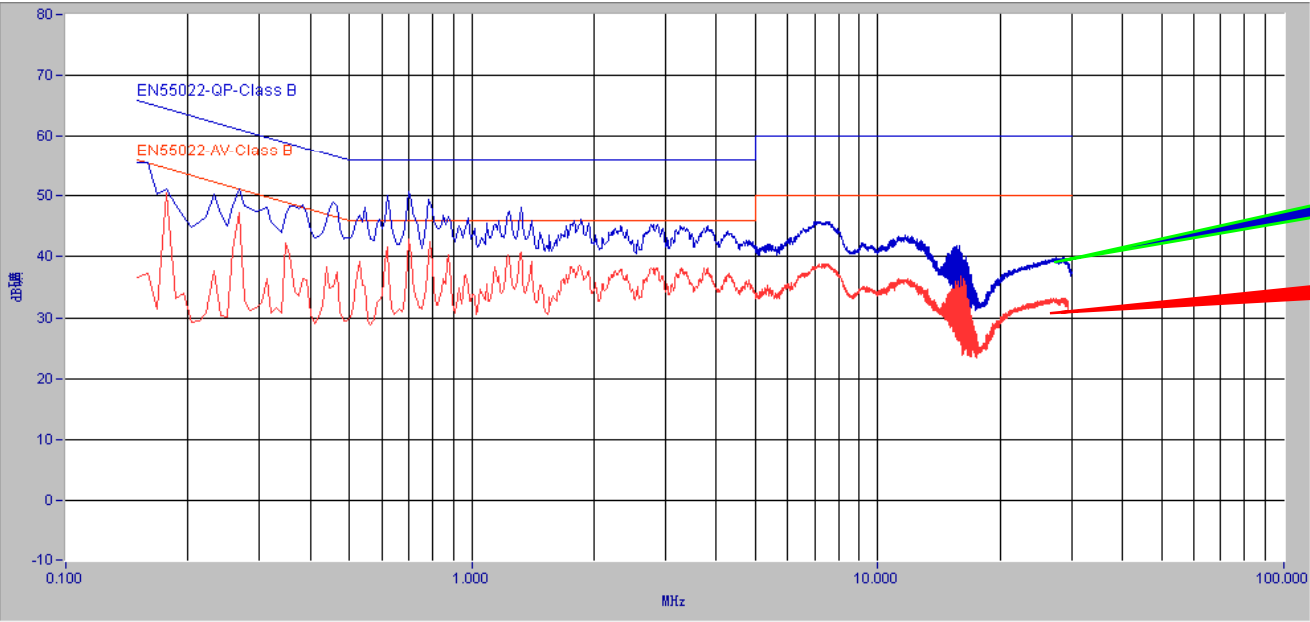


QP Scan  
QP Limit line

AV Scan  
AV Limit line

Input=115VAC  
N line QP&AV scan

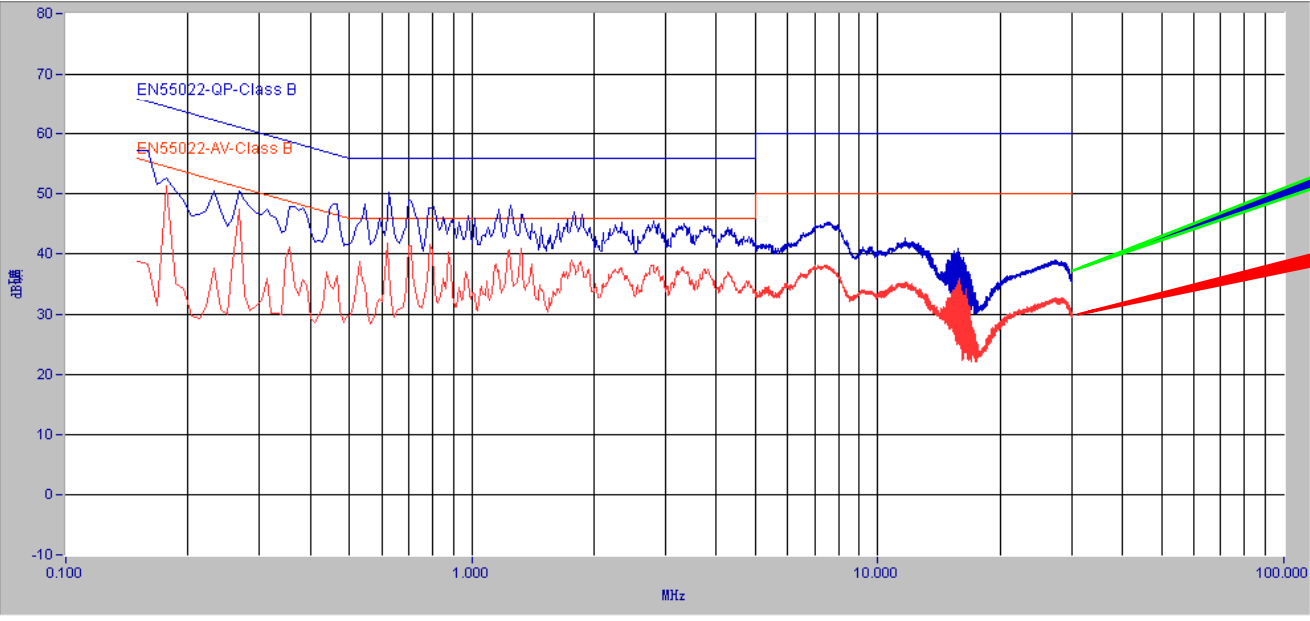
# 24. Conducted EMI (Full Load)



QP Scan  
QP Limit line

AV Scan  
AV Limit line

Input=230VAC  
L line QP&AV scan

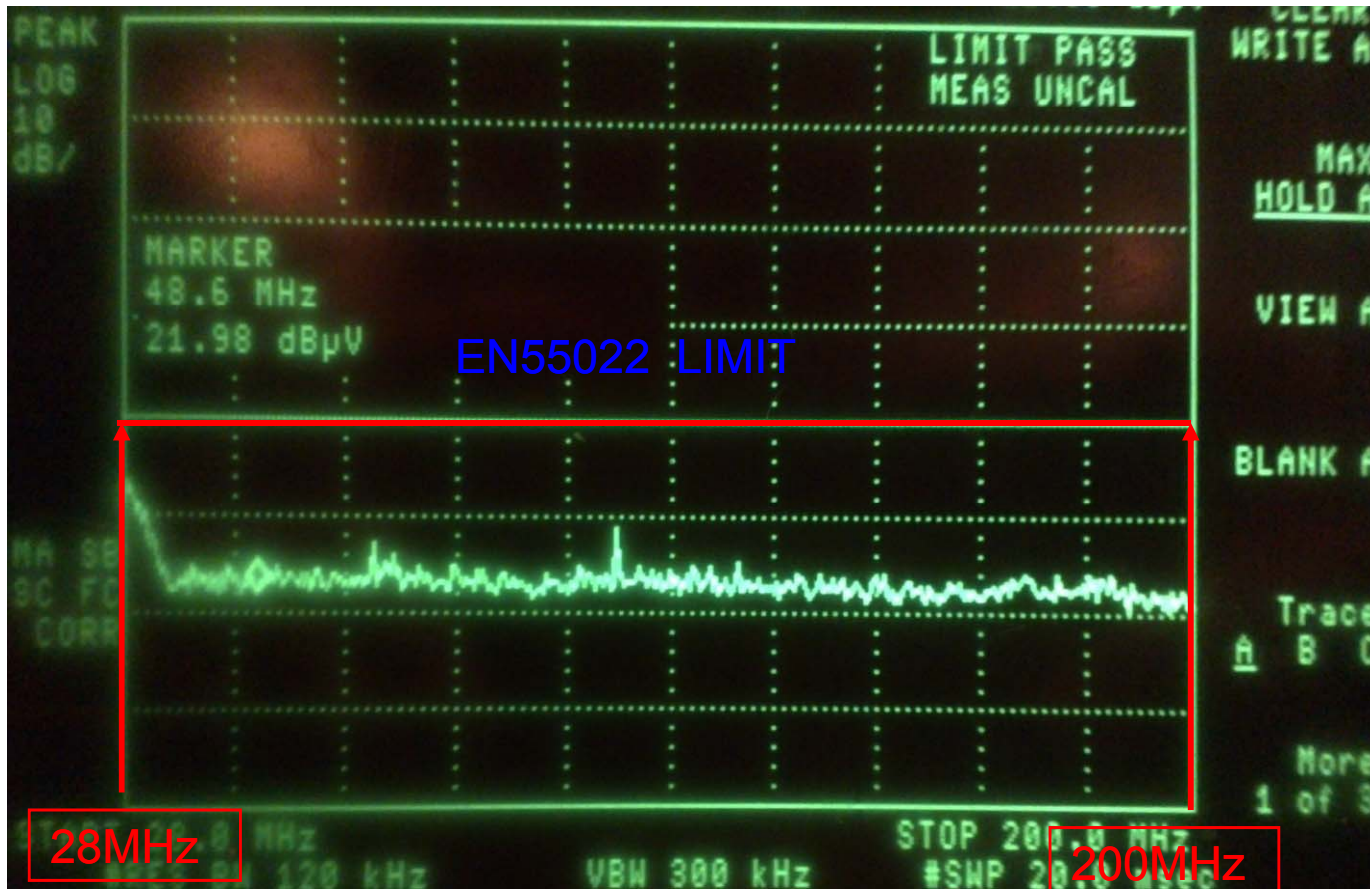


QP Scan  
QP Limit line

AV Scan  
AV Limit line

Input=230VAC  
N line QP&AV scan

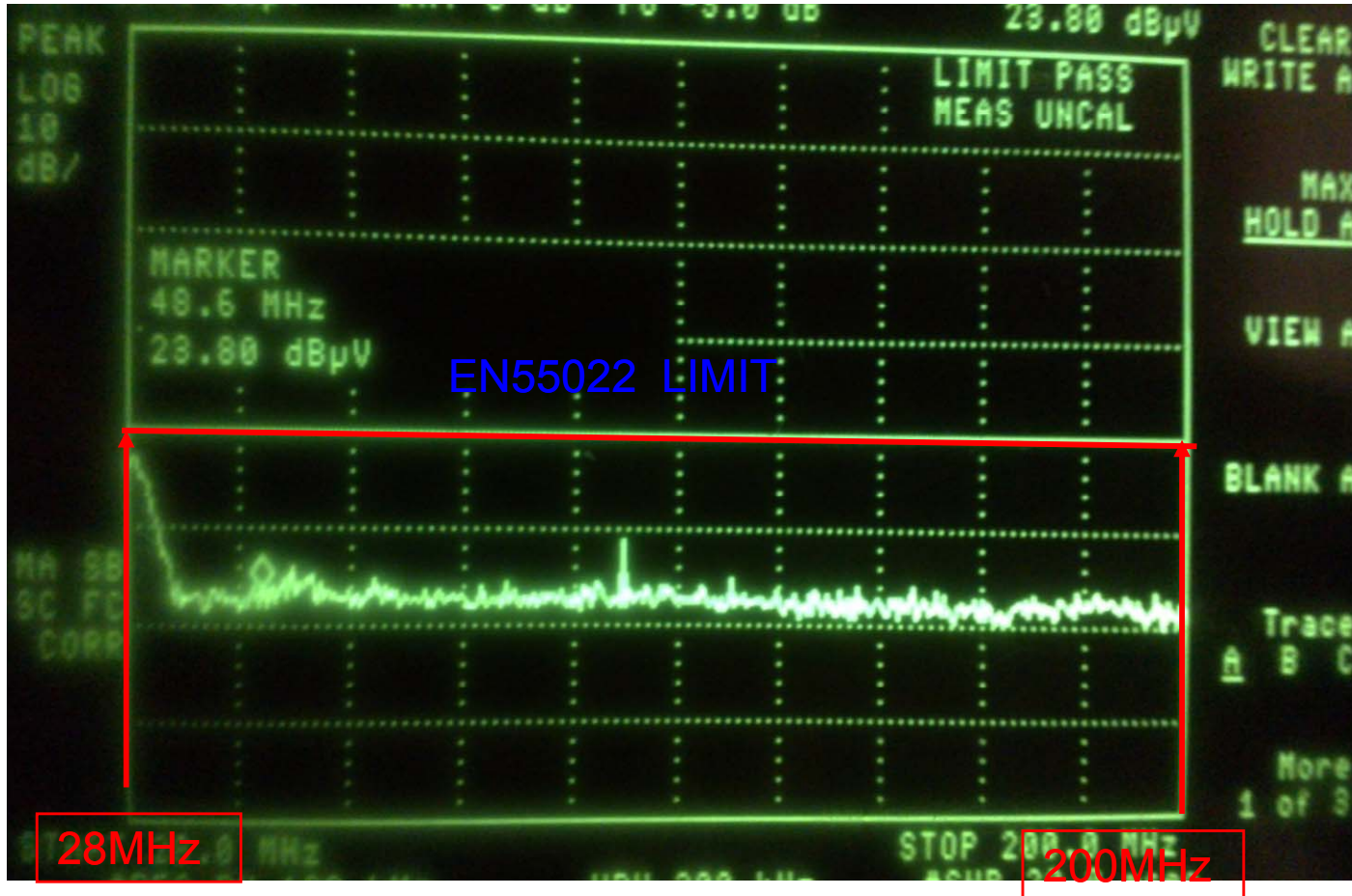
# 25. Radiated EMI ( Reference only)



Note: 1, Vin=115Vac

2, Output is floating

# 26. Radiated EMI (Reference only)



Note: 1,  $V_{in}=230V_{ac}$   
2, Output is floating